



Future Needs related to Inline Metrology applied in Semiconductor Manufacturing

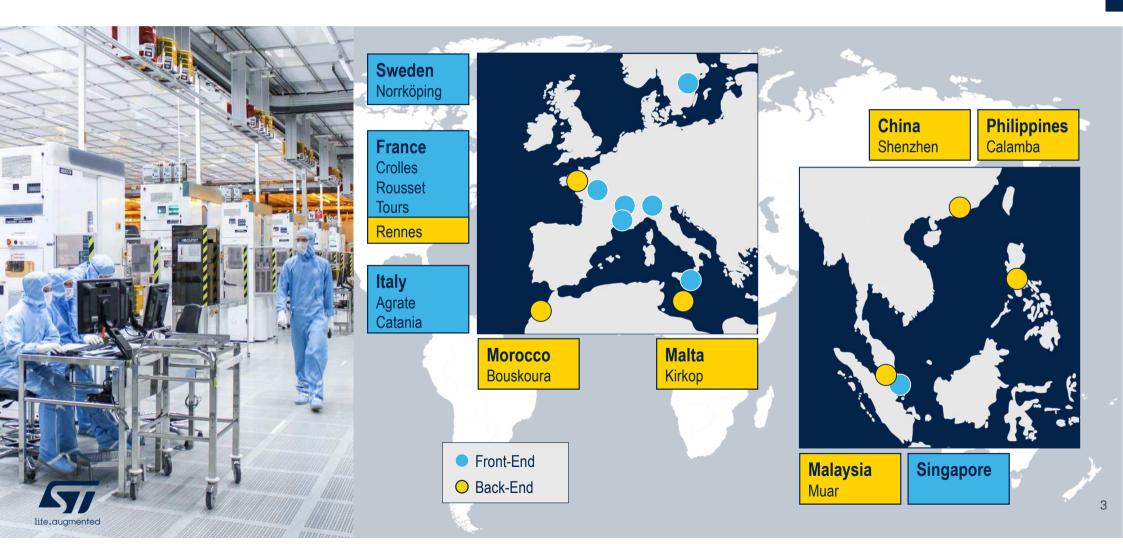
STMicroelectronics

D. Le Cunff, Ph.D 8th July 2022

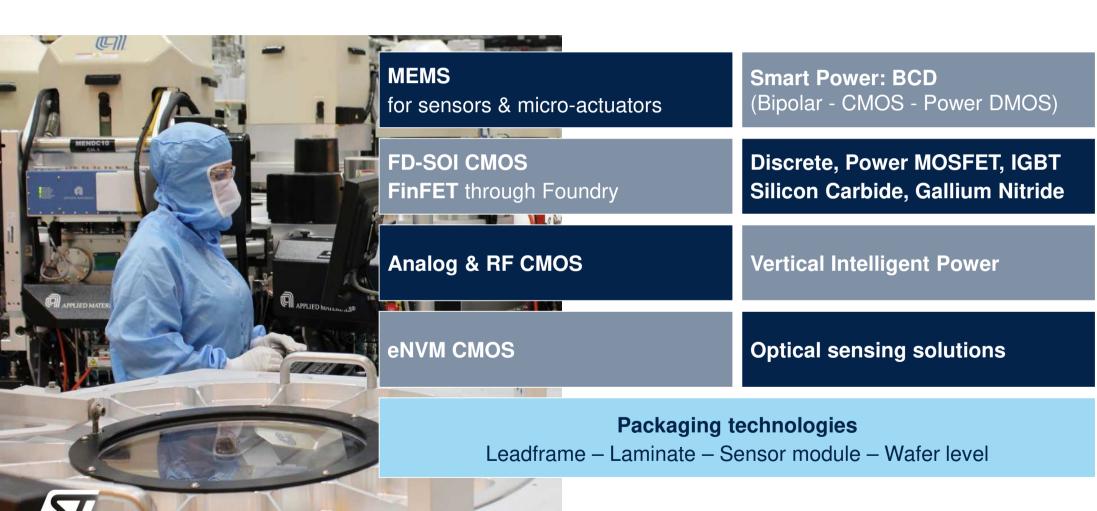
We are creators and makers of technology



We offer quality, flexibility and supply security



Differentiated technologies are our foundation







STMicroelectronics Europe

Two of the most modern and efficient clean rooms worldwide



Equipped with automated transport system form the ceiling

Crolles & Agrate 300mm Factory 4.0 Industry

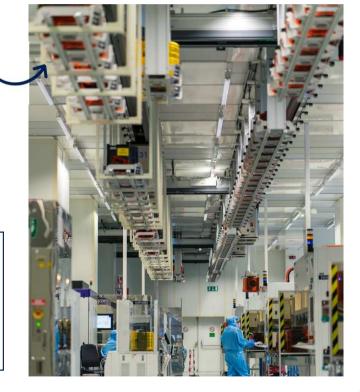


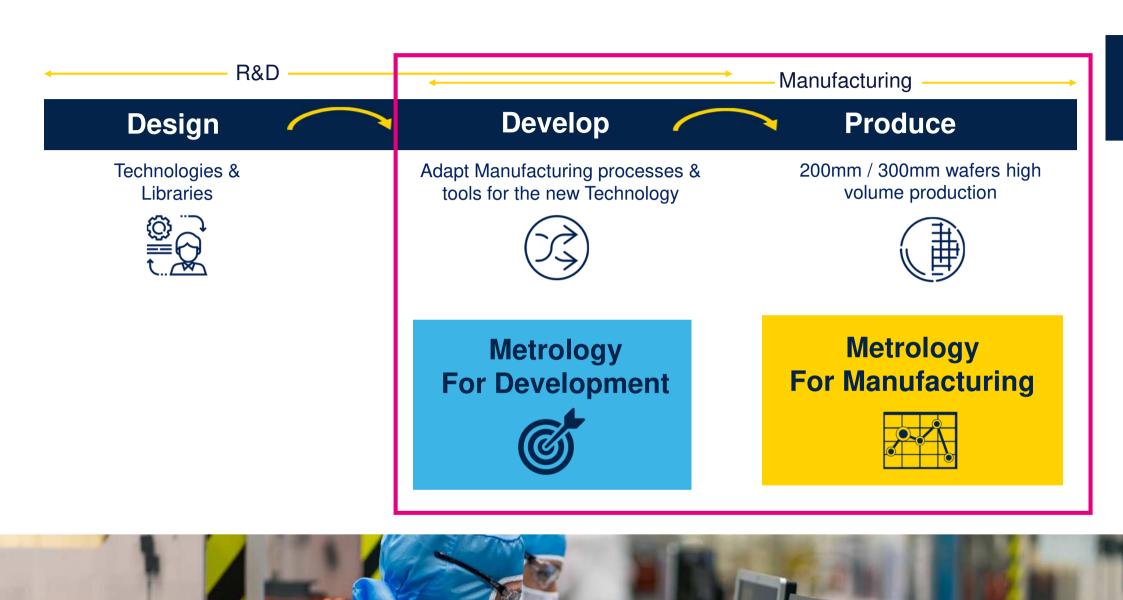
Bundle of manufacture are going to move from one production to many others to go through all the operations needed,

without ever passing between human's hands.

Human takes action on the maintenance of device and the implementation













Produce



Metrology For Development

Provide measurement solution to secure learning cycles and support critical decision for quick path finder



Advanced Materials & Architectures



Reference standards



Metrology For Manufacturing

Control and Detect process deviation through optimized sampling plan based on risk analysis



Optimization & Better Control



Smart approaches











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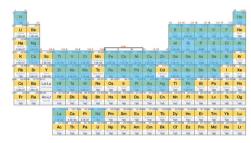


Smart approaches





Advanced Materials & Structures



New material and chemical element introduction

New characteristics «More than Moore»:

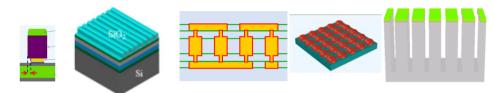
- Optical transmission or emission
- Mechanical and thermal properties
- Stress, Adhesion
- Piezoelectrical

Complementary techniques needed

Multi physics and multi scale modeling

Transfer lab to fabs

- Quick time to solution via collaboration
- Introduction in fab at early TRL



Advanced CMOS

Large pitch and 3D structures

Deep trenches

Complex scaled structures

- 3D profile
- Massive measurement uniformity/EPE

High AR or Large pitch

Small feature on large structures

Metrology target representativity

- Indie measurement / ML algorithm
- Edge of wafer

E-Beam, Scatterometry, CD-SAXS, SPM...

Ellipsometry, X-Ray, Acoustics, Raman, electrical...







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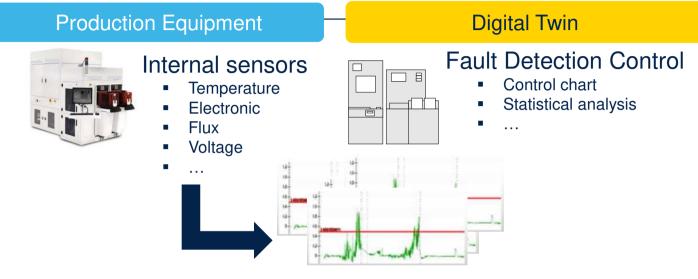


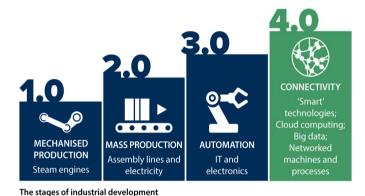
Smart approaches



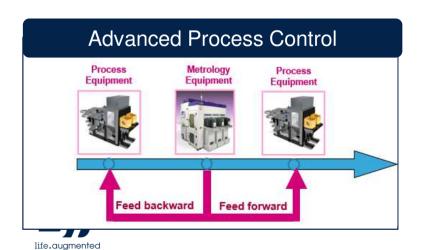


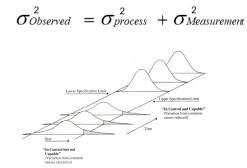
Data / Sensors

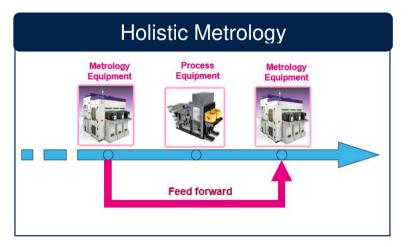


















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Virtual Fab Strategy

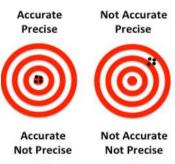
Quick and Safe Technology Transfer

Mutualisation of Fab manufacturing Capacity

Alignment between fab metrologies is a pre-request

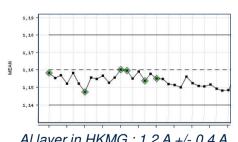
Need for reference standards:

- Industrial, stable over time and usage
- Cover all metrology techniques and ranges









Al layer in HKMG: 1.2 A +/- 0.4 A

- Multiples system → Virtuous cycle
- Precision requirements are more agressive than accuracy uncertainty







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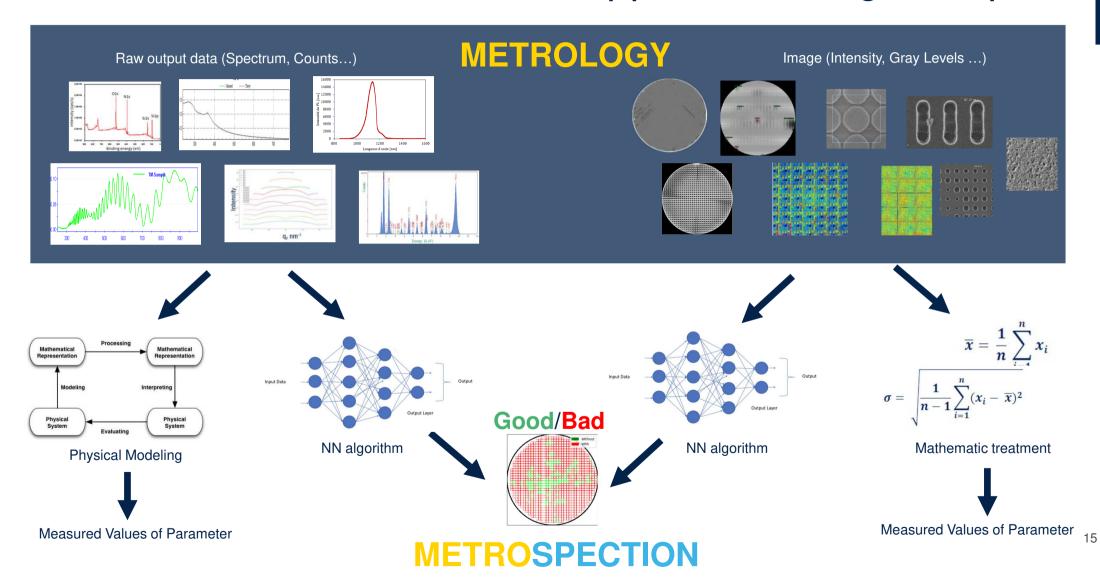


Smart approaches





Al Approach - Large Adoption









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Smart approaches



Need young talent







Our technology starts with You

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EMPIR: Support Letter for **ATMOC** and **ELENA**

Joined Research Projects



Some on going projects



MADEin4 aims to bring production lines to a next level in productivity and predictability by focusing on two **boosters**; while fulfilling and/or exceeding also sensitivity, precision and accuracy requirements:

- Productivity booster 1: High throughput, next generation metrology and inspection tools development. This
 booster, yielding connected Cyber Physical Systems (CPS) enabling very high sampling and data-rates, will
 be developed by the metrology equipment manufacturers, module suppliers and knowledge institutes and
 will be demonstrated in an industry 4.0 pilot line at IMEC. It will address major challenges for ECS
 equipment, materials and manufacturing industries.
- Productivity booster 2: Develop combinations of Design (EDA), Product/process Life Cycle Management
 (PLM), modelling, simulations and advanced metrology data analysis with Machine Learning (ML), Digital
 Twinning and predictive diagnostics of the process (predictive yield) and tools performance. This booster
 will be developed and demonstrated in an industry 4.0 pilot line at IMEC, by the EDA, and by computing
 and metrology partners. The digital twinning and predictive maintenance concepts will be demonstrated in
 two major 'digital industries': semiconductor industry and automotive production.



CHALLENGES consortium is composed by **14 partners** from 7 Countries:

5 EU Countries (Belgium, France, Germany, Italy, Spain)

and 2 H2020-associated Countries (Israel and Belarus)





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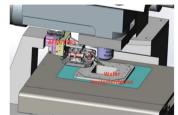


Figure 2 CAD design of the AFM proposed by NANONICS

The project Real-time nano-CHAracterization related techNoloGiEeS — CHALLENGES—aims to develop innovative Non-Destructive Techniques (NDTs) for reliable inline multiscale measurements down to the nanoscale, and fully compatible with different factory environments. The developed metrology technologies will enable the increase of speed, resolution, sensitivity, spectral range and compatibility within different nanorelated production environments, finally improving products performance, quality and reliability, with the consequent bosting of competitiveness. The CHALLENGES's innovation will be developed exploiting the plasmonic enhancement of optical signals. It will provide a non-destructive approach based on the use of multipurpose nano-optical techniques to enable a reliable real-time nano-scale characterization in the factory floor, using plasmonic enhanced Raman, InfraRed (IR) and Photoluminescence signals.

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